

NPN LOW POWER SILICON TRANSISTOR

Qualified per MIL-PRF-19500/368

Devices

2N3439 **2N3440**
2N3439L **2N3440L**

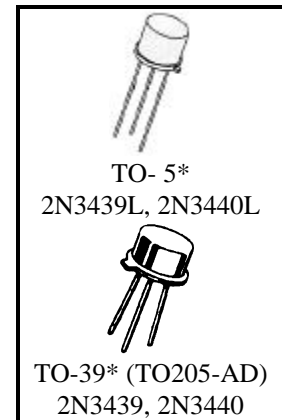
Qualified Level

JANTX
JANTXV

MAXIMUM RATINGS

| Ratings | Symbol | 2N3439 | 2N3440 | Units |
|---------------------------------------|-------------------|-----------------------------|--------|----------------|
| Collector-Emitter Voltage | V_{CEO} | 350 | 250 | Vdc |
| Collector-Base Voltage | V_{CBO} | 450 | 300 | Vdc |
| Emitter-Base Voltage | V_{EBO} | 7.0 | | Vdc |
| Collector Current | I_C | 1.0 | | Adc |
| Total Power Dissipation | P_T | @ $T_A = 25^{\circ}C^{(1)}$ | 0.8 | W |
| | | @ $T_C = 25^{\circ}C^{(2)}$ | 5.0 | W/ $^{\circ}C$ |
| Operating & Storage Temperature Range | T_{op}, T_{stg} | -55 to +200 | | $^{\circ}C$ |

- 1) Derate linearly 4.57 mW/ $^{\circ}C$ for $T_A > +25^{\circ}C$
- 2) Derate linearly 28.5 mW/ $^{\circ}C$ for $T_C > +25^{\circ}C$



*See Appendix A for Package Outline

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

| Characteristics | Symbol | Min. | Max. | Unit |
|-----------------|--------|------|------|------|
|-----------------|--------|------|------|------|

OFF CHARACTERISTICS

| | | | | |
|--|------------------|---------------|------------|------------------------|
| Collector-Emitter Breakdown Voltage $I_C = 50$ mAdc | 2N3439 2N3440 | $V_{(BR)CEO}$ | 350 250 | Vdc |
| Collector-Emitter Cutoff Current $V_{CE} = 300$ Vdc $V_{CE} = 200$ Vdc | 2N3439 2N3440 | I_{CEO} | 2.0 2.0 | μ Adc μ Adc |
| Emitter-Base Cutoff Current $V_{EB} = 7.0$ Vdc | | I_{EBO} | 10 | μ Adc |

ELECTRICAL CHARACTERISTICS (con't)

| Characteristics | Symbol | Min. | Max. | Unit |
|---|-----------|------|--------------------------|--------------------------------------|
| OFF CHARACTERISTICS (con't) | | | | |
| Collector-Emitter Cutoff Current $V_{CE} = 450 \text{ Vdc}, V_{BE} = -1.5 \text{ Vdc}$ $V_{CE} = 300 \text{ Vdc}, V_{BE} = -1.5 \text{ Vdc}$ | I_{CEX} | | 5.0 5.0 | $\mu\text{A dc}$ $\mu\text{A dc}$ |
| Collector-Base Cutoff Current $V_{CB} = 360 \text{ Vdc}$ $V_{CB} = 250 \text{ Vdc}$ $V_{CB} = 450 \text{ Vdc}$ $V_{CB} = 300 \text{ Vdc}$ | I_{CBO} | | 2.0 2.0 5.0 5.0 | $\mu\text{A dc}$ |

ON CHARACTERISTICS ⁽³⁾

| | | | | |
|---|---------------|----------------|-----|-----|
| Forward-Current Transfer Ratio $I_C = 20 \text{ mA dc}, V_{CE} = 10 \text{ Vdc}$ $I_C = 2.0 \text{ mA dc}, V_{CE} = 10 \text{ Vdc}$ $I_C = 0.2 \text{ mA dc}, V_{CE} = 10 \text{ Vdc}$ | h_{FE} | 40 30 10 | 160 | |
| Collector-Emitter Saturation Voltage $I_C = 50 \text{ mA dc}, I_B = 4.0 \text{ mA dc}$ | $V_{CE(sat)}$ | | 0.5 | Vdc |
| Base-Emitter Saturation Voltage $I_C = 50 \text{ mA dc}, I_B = 4.0 \text{ mA dc}$ | $V_{BE(sat)}$ | | 1.3 | Vdc |

DYNAMIC CHARACTERISTICS

| | | | | |
|---|------------|-----|----|----|
| Magnitude of Common Emitter Small-Signal Short-Circuit Forward Current Transfer Ratio $I_C = 10 \text{ mA dc}, V_{CE} = 10 \text{ Vdc}, f = 5.0 \text{ MHz}$ | $ h_{fe} $ | 3.0 | 15 | |
| Forward Current Transfer Ratio $I_C = 5.0 \text{ mA dc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}$ | h_{fe} | 25 | | |
| Output Capacitance $V_{CB} = 10 \text{ Vdc}, I_E = 0, 100 \text{ kHz} \leq f \leq 1.0 \text{ MHz}$ | C_{obo} | | 10 | pF |
| Input Capacitance $V_{EB} = 5.0 \text{ Vdc}, I_C = 0, 100 \text{ kHz} \leq f \leq 1.0 \text{ MHz}$ | C_{ibo} | | 75 | pF |

SWITCHING CHARACTERISTICS

| | | | | |
|---|-----------|--|-----|---------------|
| Turn-On Time $V_{CC} = 200 \text{ Vdc}; I_C = 20 \text{ mA dc}, I_{B1} = 2.0 \text{ mA dc}$ | t_{on} | | 1.0 | μs |
| Turn-Off Time $V_{CC} = 200 \text{ Vdc}; I_C = 20 \text{ mA dc}, I_{B1} = -I_{B2} = 2.0 \text{ mA dc}$ | t_{off} | | 10 | μs |

SAFE OPERATING AREA

| | | | | |
|---|--|--|--|--|
| DC Tests $T_C = 25^\circ\text{C}, 1 \text{ cycle}, t = 1.0 \text{ s}$ | | | | |
| Test 1 $V_{CE} = 5.0 \text{ Vdc}, I_C = 1.0 \text{ A dc}$ Both Types | | | | |
| Test 2 $V_{CE} = 350 \text{ Vdc}, I_C = 14 \text{ mA dc}$ 2N3439 | | | | |
| Test 3 $V_{CE} = 250 \text{ Vdc}, I_C = 20 \text{ mA dc}$ 2N3440 | | | | |

(3) Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2.0\%$.



LittleDiode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

LittleDiode.com

Looking forward to providing you with the best possible service.